

RELIABILITY REPORT FOR

MAX9637AXA+T

PLASTIC ENCAPSULATED DEVICES

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MAXIM INTEGRATED

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Approved by
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Conclusion

The MAX9637AXA+T successfully meets the quality and reliability standards required of all Maxim Integrated products. In addition, Maxim Integrated's continuous reliability monitoring program ensures that all outgoing product will continue to meet Maxim Integrated's quality and reliability standards.

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I. Device Description

A. General

The MAX9636/MAX9637/MAX9638 are single-supply, CMOS input op amps featuring wide bandwidth at low quiescent current, making them suitable for a broad range of battery-powered applications such as portable medical instruments, portable media players, and smoke detectors. A combination of extremely low input bias currents, low input current noise and low input voltage noise allows interface to high-impedance sources such as photodiode and piezoelectric sensors. These devices are also ideal for general-purpose signal processing functions such as filtering and amplification in a broad range of portable, battery-powered applications. The ICs feature a maximized ratio of gain bandwidth (GBW) to supply current. The devices operate from a single 2.1V to 5.5V supply at a typical quiescent supply current of 36µA. For additional power conservation, the MAX9636 and MAX9638 offer a low-power shutdown mode that reduces supply current to 1µA and places the amplifiers' outputs into a high-impedance state. The ICs are specified over the automotive operating temperature range (-40°C to +125°C). The single is offered in a space-saving, 6-pin SC70 package, while the dual is offered in tiny, 8-pin SC70 and 10-pin UTQFN packages.



II. Manufacturing Information

A. Description/Function: 3V/5V Low-Power, Low-Noise, CMOS, Rail-to-Rail I/O Op Amps

B. Process: S18
C. Number of Device Transistors: 740
D. Fabrication Location: California
E. Assembly Location: Thailand

F. Date of Initial Production: September 17, 2010

III. Packaging Information

A. Package Type: 8L SC70
B. Lead Frame: Copper
C. Lead Finish: NiPdAu

D. Die Attach: Non-conductive
E. Bondwire: Au (1 mil dia.)
F. Mold Material: Epoxy with silica filler
G. Assembly Diagram: #05-9000-4217
H. Flammability Rating: Class UL94-V0

Classification of Moisture Sensitivity per

JEDEC standard J-STD-020-C

J. Single Layer Theta Ja: 326°C/W
K. Single Layer Theta Jc: 115°C/W
L. Multi Layer Theta Ja: 326°C/W
M. Multi Layer Theta Jc: 115°C/W

IV. Die Information

A. Dimensions: 30.31 X 35.43 mils

B. Passivation: Si₃N₄/SiO₂ (Silicon nitride/ Silicon dioxide)

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C. Interconnect: Al with Ti/TiN Barrier

D. Backside Metallization: NoneE. Minimum Metal Width: 0.18umF. Minimum Metal Spacing: 0.18um

G. Bondpad Dimensions:

H. Isolation Dielectric: SiO₂I. Die Separation Method: Wafer Saw



V. Quality Assurance Information

A. Quality Assurance Contacts: Richard Aburano (Manager, Reliability Engineering)

Don Lipps (Manager, Reliability Engineering) Bryan Preeshl (Vice President of QA)

B. Outgoing Inspection Level: 0.1% for all electrical parameters guaranteed by the Datasheet.

0.1% For all Visual Defects.

C. Observed Outgoing Defect Rate: < 50 ppm
D. Sampling Plan: Mil-Std-105D

VI. Reliability Evaluation

A. Accelerated Life Test

The results of the 135¿C biased (static) life test are shown in Table 1. Using these results, the Failure Rate (3) is calculated as follows:

$$\lambda = 1 = 1.83$$
 (Chi square value for MTTF upper limit)

MTTF 192 x 4340 x 48 x 2

(where 4340 = Temperature Acceleration factor assuming an activation energy of 0.8eV)

 $\lambda = 22.9 \times 10^{-9}$

x = 22.9 F.I.T. (60% confidence level @ 25°C)

The following failure rate represents data collected from Maxim Integrated's reliability monitor program. Maxim Integrated performs quarterly life test monitors on its processes. This data is published in the Reliability Report found at http://www.maximintegrated.com/qa/reliability/monitor. Cumulative monitor data for the S18 Process results in a FIT Rate of 0.40 @ 25C and 6.96 @ 55C (0.8 eV, 60% UCL)

B. E.S.D. and Latch-Up Testing (lot SQ6ZAQ002A D/C 1029)

The OY56-1 die type has been found to have all pins able to withstand a HBM transient pulse of +/-2500V per JEDEC JESD22-A114. Latch-Up testing has shown that this device withstands a current of +/-250mA and overvoltage per JEDEC JESD78.



Table 1Reliability Evaluation Test Results

MAX9637AXA+T

TEST ITEM	TEST CONDITION	FAILURE IDENTIFICATION	SAMPLE SIZE	NUMBER OF FAILURES	COMMENTS
Static Life Test	(Note 1) Ta = 135°C Biased	DC Parameters & functionality	48	0	SQ6YAQ002A, D/C 1029
	Time = 192 hrs.				

Note 1: Life Test Data may represent plastic DIP qualification lots.